Charge Halle ect driven by spin-dependent chem ical potential gradients and Onsager relations in mesoscopic systems

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We study theoretically the spin-Hall e ect as well as its reciprocal phenom enon (a transverse charge current driven by a spin-dependent chem ical potential gradient) in electron and hole nite size mesoscopic system s. The Landauer-Buttiker-K eldysh form alism is used to model sam ples with mobilities and R ashba coupling strengths which are experimentally accessible and to demonstrate the appearance of measurable charge currents induced by the spin-dependent chem ical potential gradient in the reciprocal spin-Halle ect. We also demonstrate that within the mesoscopic coherent transport regime the 0 nsager relations are fullled for the disorder averaged conductances for electron and hole mesoscopic system s.

Introduction. In the very active eld of sem iconductor based spintronics the control of spin can be achieved by the manipulation of the strength of spin-orbit (SO) interactions in param agnetic system s. W ithin this context, the new ly proposed intrinsic spin-Halle ect (SHE) in p-doped sem iconductors by M urakam ietal.[1] and in a two-dimensional electron system (2DES) by Sinova et al. [2] o ers new possibilities for spin current manipulation and generation in high mobility param agnetic sem iconductor system s. In contrast to the earlier proposed extrinsic spin-Halle ect [3, 4, 5], which is associated with scattering from in purities, the intrinsic spin-Hall arises purely from host sem iconductor band structure and represents a spin-current response generated perpendicular to the driving electric eld.

Recently, the spin Halle ect was experimentally observed by K ato et al. [6] in n-doped G aA s using the K err e ect and by W underlich et al. [7] in the p-n junction light-em itting diodes based on two dimensional hole gas (2D HG) (A LG a) As. A though, the experiment by W underlich et al. seems to be in the regime where the intrinsice ect in 2DHG is dom inant, the main theoretical focus has been concentrated so far on 2DEG with Rashba SO interactions, where Rashba term is linear with k [2, 8, 9, 10, 11, 12, 13, 14, 15, 16, 17, 18, 19, 20, 21]. The in uence of disorder on in nite 2DEG is still unclear (for a recent review see [21]). For -function in purities the analytical calculations of vertex corrections in the ladder approximation seem to cancel the intrinsic spin-Halle ect in a weak scattering regim e [12, 14]. However, these calculations have been challenged recently [20]. Furtherm ore, the num erical calculations based on K ubo form ula using continuum model in momentum space [13] and discrete m odel in the real space [22] show nite spin-conductivity in a weak scattering regime which goes to zero in the therm odynam ic lim it for electron system s [22, 23]. In contrast, for the in nite 2DHG the vertex corrections vanish [24, 25]. Moreover, the num erical calculations based on Kubo formula using continuum model in mom entum space show nite value of SHE in a weak scattering regim e w hich goes to constant in the therm odynam ic lim it [23].

The calculations within the Landauer-Buttiker (LB) form alism on nite size systems [17, 18, 19, 26] model a sam ple of micro/nanosize attached to contacts. The calculations on electron m esoscopic systems show that spin H all conductance is a fraction of e=8 in a weak scattering regime [17, 18, 19]. Moreover, a mesoscopic spin-H all conductance is robust against the disorder [17, 18, 19]. Very recently W u and Zhou considered the Luttinger model [27], showing as expected that SHE can be much larger in hole systems in comparison with the electron ones. A lthough the experimental measurem ent by W underlich at al [7] concern 2D HG systems with broken inversion symmetry, the pure cubic Rashba term was not considered in detail within the LB form alism so far.

The observation of spin-Halle ect through transport m easurem ents is one of the urgent experim ental challenges facing this spin-transport physics. Recently, an H-probe structure has been proposed to measure the effect where the spin-Halle ect could be measured indirectly by detecting charge voltages induced by the reciprocal spin-Halle ect (RSHE) [19]. This RSHE, where transverse charge current is driven by spin dependent chemical potential, was proposed in a context of extrinsic spin-Halle ect by Hirsch [4] and formulated in a sem iclassical approach by Zhang and Niu [28]. Also, the Onsager relation between the spin-Hall conductivity and reciprocal charge-H all conductivity was established within a wave packet model through a rede nition of the spin-current including spin-torque term s in the bulk [28]. We show here that within the mesoscopic regime, and more speci cally within the Landauer-Buttiker-Keldysh form alism, the Onsager relations are satis ed within the m odels studied for the disorder averaged conductances. Because the conductances are formulated with respect to the leads which have no spin-orbit coupling, it is not necessary nor consequential to introduce the spin current

rede nition in our problem [28].

In this paper we com pare the m agnitude of the SHE as well as the RSHE in nite electron and hole m esoscopic system swithin the LB form alism . We show that the conductances associated with both e ects are signi cantly larger in the hole system s. Furtherm ore, we analyze the possible experimental setup to measure the RSHE. We show that the charge current driven by a spin-dependent chem icalgradient is on the order of hundred nano-am pers for typical voltages in hole system s and should be experimentally measurable.

M odel H am iltonian for hole system and LB treatment of the spin-H all e ect and its reciprocal correspondent. The observation of the spin-H all e ect and its reciprocal phenomenon in transport is the next experimental challenge in the sub eld of spintronics using spin-orbit interactions to manipulate the spin.

The continuum e ective mass model for 2D HG in a narrow inversion asymmetrical well is given by [29]: $\hat{H} = \frac{p^2}{2m} + i_{2-3} (p^3 \uparrow_+ p_+^3 \uparrow_-) + H_{dis}$, where H_{dis} describes disorder. We use the tight-binding approximation [30] to model the disordered conductor within the LB form alism. W ithin this approximation the continuum e ective mass envelope function H am iltonian becomes:

$$H = X X X Y J_{j}, C_{j}, C_$$

where t = $\sim^2 = 2m a_0^2$ and t_{SO k³} = $= 2a_0^3$, a_0 is the m esh lattice spacing, and $\sim = a_0 \hat{x}$; $a_0 \hat{y}$. The rst term represents a quenched disorder potential and disorder is introduced by random ly selecting the on-site energy $_j$ in the range [W /2,W /2]. The continuum e ective m ass m odel for 2D E S and its tight-binding correspondent can be found elsewhere [18, 19].

W ithin the leads the SO coupling is zero and therefore each lead should be considered as having two independent spin-channels. Moreover, in leads without the SO coupling, the spin current is measured in a medium where spin is conserved removing the ambiguity of spin-current de nition. For SHE, leads constitute reservoirs of electrons at chemical potential $_1;:::;_N$,



FIG.1: The schematic picture of setup to measure (a) charge Halle ect driven by spin dependent chemical potential and (b) spin-Halle ect.



FIG.2: Proposal of experim ental setup to measure the reciprocal spin-Hall e ect. a) Mask (light-gray) covers a sample and leads except for two holes in the longitudinal leads where circularly polarized light shines. (b) Full schematics of the experimental set-up.

where N is the number of leads that we consider to be four (see Fig. 1b). For RSHE, the chem ical potential is spin dependent in leads 1 and 2 allowing the generation of spin-force in the x direction (see Fig. 1a). In the low temperature limit $k_B T << E_F$ and for low bias-voltage, the particle current going through a particular channel is given within the LB form alism by [30] $I_{p_7} = (e=h) \int_{q_1} \circ T_{p_7} : g_1 \circ V_q$, where p labels the

lead and $T_{p; \ R; 0}$ is the transmission coe cient at the Ferm i energy E_F between the (p;) channel and the (q; ⁰) channel. This transmission coe cient is obtained by $T_{p; \ R; 0} = Tr[p; G^R q; \circ G^A]$ where p; is given by p; (i; j) = i[$\frac{R}{p}$; (i; j) $\stackrel{A}{p}$; (i; j)]. The retarded and advance G reen's function of the sam ple $G^{R=A}$ with the leads taken into account through the self energy $\frac{R=A}{p;}$ (i; j)] ¹. Here the position representation of the sam ple G^{R} , $H_{i;j}$, and R are in the subspace of the sam ple. Within the above form alism the spin gurrent through each channel is given by $I_{p;}^{s} = (e=4) \int_{q=0}^{R} T_{p; \ R; 0} [N_{p;} V_{q; 0}]$. The spin force driven charge H all conductance, G_{CS}^{yx} , is de ned as the ratio of charge current in the y-direction induced by the spin-dependent chem ical potential difference (see F ig 1a).

$$G_{CS}^{YX} = \frac{(I_{3"}^{S} + I_{3\#}^{S})}{V_{2}^{"} V_{1}^{"}}; \qquad (2)$$

where $V_i^{"} = [-e]_i = e$. The spin-H all conductance \mathcal{G}_{SC}^{xy} , is de ned as the ratio of spin-current in the x-direction induced by charge voltage di erence in y direction to this voltage di erence

$$G_{SC}^{xy} = \frac{(I_{1*}^{s} \quad I_{1\#}^{s})}{V_{4} \quad V_{3}};$$
(3)

where $V_i = i=e$, and the labels are indicated in Fig.1b. G_{SC}^{yx} and G_{CS}^{xy} are de ned by analogy. We set the absolute value of voltage for spin and spin force driven charge-Halle ects as V = =e = 2.5 m V.



FIG.3: The spin-force driven charge current as a function of electron concentration and R ashba coupling, , form esoscopic square sample 100nm by 100nm and $= 250,000 \text{ cm}^2/\text{V} \text{ s.}$

Results and discussion. In order to address the key issue of experimental observation of spin driven charge-Hall e ect as well as to establish the Onsager relation between spin-Halle ect and it reciprocal correspondent we choose realistic param eters for our calculations which m odel currently attainable system s. We consider an effective mass of m = 0.05 m_{e} for electron system s and m = 0.5 m_{e} for hole ones. The disorder strength W = 0.09 m eV corresponds to the mobility of 250,000 cm²/Vs, which is typical for a sem iconductor like (In,G a)As. We take the Rashba param eter in the range from 0 to 100 m eV nm, easily obtained in experiments [31, 32], and we choose the electron concentration n_{2D} in a range between 3 10^{11} cm^2 and 1:3 10^{21} cm^2 . The Fermi energy is obtained from the chosen carrier concentration assuming an in nite 2D gas. In the detection of spin



FIG. 4: The spin-force driven charge current as a function of hole concentration and R ashba coupling , , for m esoscopic square sample 100nm by 100nm and = 250,000 cm²/V s.

force driven charge-Halle ect the rst task is to generate a spin force which can be realized by spin dependent chem ical potential in the leads. The ferrom agnetic leads are not the good candidates because although m agnetization exists in ferrom agnetic leads, the chem ical potential is the same for both spin directions. Here, we propose the opticalm ethod of spin-dependent chem ical potential generation by shining the beam of circularly polarized light on the leads (see Fig. 2). The right-circularly polarized beam shines on the right lead (lead 2 in Fig.1a) and the left circularly polarized beam on the left one (lead 1 in Fig.1a). The sample as well as the transverse leads should be covered by mask, preventing the light absorption anywhere except the small part of longitudinal leads as shown in Fig.2a. Choosing sem iconductor leads for this setup e.g. G aAs, will cause the opposite spin polarizations in left and right leads through optical selection rules. Using the beam splitter should produce the same light intensity in each leads providing simultaneously the spin-dependent chem ical potential between leads 1 and 2 and the total charge current across a sam ple equal zero. Having produced the spin-dependent chem i-

calpotential in the leads, we perform calculations using non-equilibrium G reen function m ethod presented in previous section. Fig.3 and Fig.4 present the charge current $I_3 = I_{3*}^s + I_{3\#}^s$ (see sample con guration Fig. 1a) as a function of SO coupling and electron or hole concentrations, respectively. The charge current for electron systems show oscillations with respect to the electron density and SO coupling. The period of current oscillations depends on system size, how ever its maxim al value seems to be around 40nA for systems sizes achievable in our calculations. For hole m esoscopic system s (see Fig.4), the charge current also oscillates with and for system sizes on the order of 100 nanom eteres is on the order of hundred nano-am pers in a wide range of densities starting from 6 $1b^1$ cm². Hence the charge current is much larger in hole systems and shall be detectable in experim ents. Fig.5 presents the spin-Hall conductance G_{SC}^{YX} as



FIG. 5: The spin-Hall conductance as a function of SO coupling for 100nm by 100nm square system for di erent concentration of holes (close sym bols) and electrons (open sym bols).

a function of for electron and hole system s. O ne can see that spin-Hall conductance (Fig.5) and spin-force driven charge conductances (see Figs.3 and 4) behave sim ilarly. Spin-Hall conductances for electron and hole system s oscillate with SO coupling. Moreover, G_{SC}^{yx} is several times larger for hole system s in com parison with electron ones, which is associated with much larger e ective mass in a case of hole systems. Let us emphasize that for electron and hole systems with the same e ective masses the spin-Hall e ect can be larger for electron systems. M oreover, in m esoscopic system s where Ferm i energy as well as multichannel e ects are important the straightforward renorm alization of e ective mass of electron and hole system s to com pare the spin-H all conductance suggested by [27] does not have to be correct. Our calculations in mesoscopic systems are in agreement with the

linear response K ubo calculation for 2D E G and 2D H G which show that spin-conductance is much more larger for hole system s [2, 29]. The sign of spin-H all and charge H all conductances in m esoscopic system s depends on the Ferm i energy.



FIG.6:0 nsager relation between the spin-H all conductance $G_{s\,c}^{xy}$ (open symbols) and spin-force driven charge H all conductance $G_{c\,s}^{yx}$ (close symbols) for di erent L by L hole system s.

The Onsager relations express the symmetry between the transport coe cients describing reciprocal processes in systems with a linear dependence of response to the driving forces. W ithin the models studied, considering disorder averaged conductances, the relations can be derived by utilizing the time reversal symmetry and the inversion symmetry on the x-y plane which relate $T_{n;m} = T_{m;n}$ and $T_{n;m} = T_{m;n}$ respectively, where ; and n;m are the spin and lead labels and a bar represents the opposite direction. Within the SHE $V_1 = V_2 = 0$ and $V_3 = V_4 = V_0=2$ following the labels of Fig. 1. W ithin the RSHE $V_3 = V_4 = 0$ and $V_1 = V_2 = s()V_0=2$ where s(") = +1 and s(#) = 1. W ithin the LB formalism and these boundary conditions we obtain for the spin-gurrent associated with the SHE I₁^{spin} $I_1'' I_1^{\#} = \frac{V_0}{2}^{T}$, s()(T_{1;3} T_{1;4}) and for the charge current associated with the RSHE $I_3^{\circ} = I_3^{"} + I_3^{\#} = \frac{V_0}{2}^{T}$; s()(T_{3;1} T_{3;2}). The above symmetries imply that T_{1;4} = T_{2;3} = T_{3;2}. This then yields $I_1^{\text{spin}} = I_3^{\text{c}}$ which implies the Onsager relation

$$G_{SC}^{xy} = G_{CS}^{yx}$$
(4)

This is veri ed num erically in Fig.6 which presents the disorder averaged spin-Hall conductance and charge Hall conductance for hole system s of di erent sizes. For a speci c disorder realization this relation does not hold and is only approximate depending on the strength of

the uctuations induced by disorder. This relation between G_{SC} and G_{CS} is consistent with predictions of sem iclassical wave-packet theory, where standard de nition of spin-current was modiled by a spin-torque term [28, 33]. However, as seen from the above derivation and noted in the introduction, our inding of an Onsager relations in mesoscopic coherent systems do not involve such spin-torque term since all spin-currents are de ned in the non-spin-orbit coupled leads.

Sum mary. We have analyzed the spin Hall e ect as well as its reciprocale ect in mesoscopic hole and electron systems. We have shown that the spin-Hall as well as the spin-dependent chem ical potential gradient driven charge Hall conductances are several times larger for hole systems. Further we have proposed the experimental setup to detect the transverse charge current driven by the spin-dependent chem ical potential gradient through transport measurements. We have show n that this charge current is of the order of hundred nano-ampers in hole systems and should be detectable. A lso, we have established a direct relation between the disorder average spin-H all conductances and their reciprocal in mesoscopic system s.

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